

Product Summary (@ T_A = +25°C)

V _{RRM} (V)	I _O (A)	V _F Max (V)	I _R Max (μA)
10	0.5	0.39	180

Features and Benefits

- Ultra-Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented Super Barrier Rectifier SBR[®] Technology
- Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Description and Applications

Packaged in the compact DFN1006 package, the Trench SBR SBRT05U10LP provides ultra-low forward voltage drop (V_F) and excellent low reverse leakage stability at high temperatures. It is ideal for use as a rectification, freewheeling or polarity protection diode in applications such as:

- SMPS
- Freewheeling Diodes
- Reverse Polarity Protection
- DC-DC Converters
- General Switching Applications

Mechanical Data

- Case: X1-DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Dot
- Terminals: Finish - NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ⁽⁴⁾
- Weight: 0.001 grams (Approximate)

X1-DFN1006-2



Top View



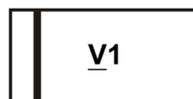
Bottom View

Ordering Information (Note 4)

Part Number	Case	Packaging
SBRT05U10LP-7B	X1-DFN1006-2	10,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



V1 = Product Type Marking Code

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	10	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_{RM}		
RMS Reverse Voltage	$V_{R(RMS)}$	14	V
Average Rectified Output Current (See Figure 1)	I_O	500	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I_{FSM}	5	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	236	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	$^\circ\text{C}$

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop	V_F	—	0.27	0.32	V	$I_F = 0.1\text{A}, T_J = +25^\circ\text{C}$
		—	0.29	0.34		$I_F = 0.2\text{A}, T_J = +25^\circ\text{C}$
		—	0.34	0.39		$I_F = 0.5\text{A}, T_J = +25^\circ\text{C}$
Leakage Current (Note 6)	I_R	—	32	180	μA mA	$V_R = 10\text{V}, T_J = +25^\circ\text{C}$
			3.4	15		$V_R = 10\text{V}, T_J = +125^\circ\text{C}$

Notes: 5. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.
6. Short duration pulse test used to minimize self-heating effect.

NOT RECOMMENDED FOR NEW DESIGN

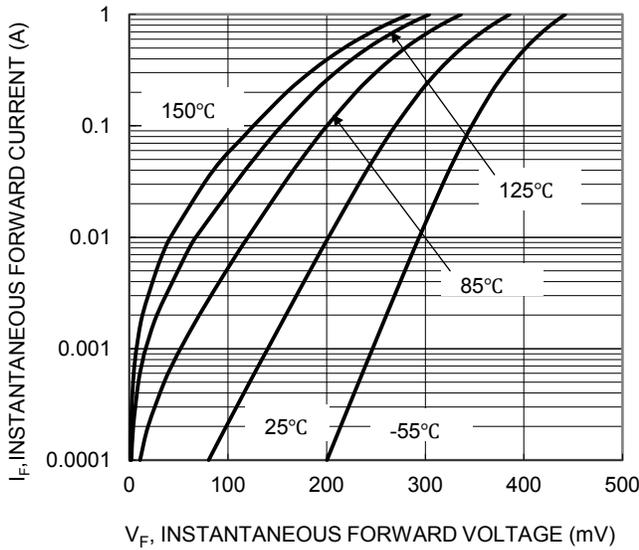


Figure 1. Typical Forward Characteristics

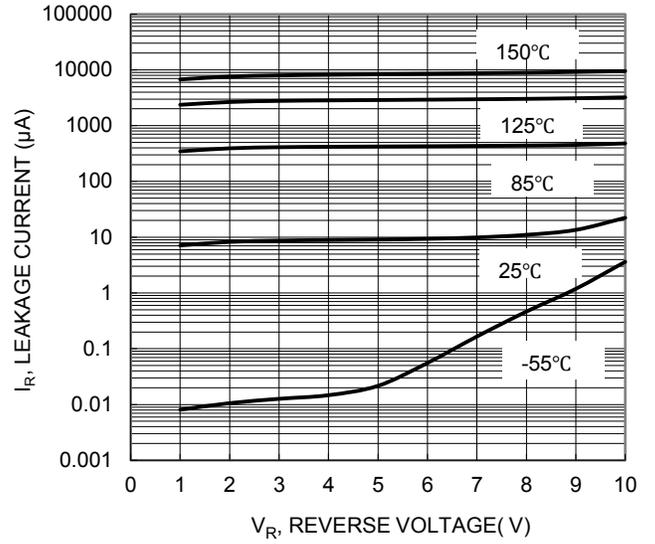


Figure 2. Typical Reverse Characteristics

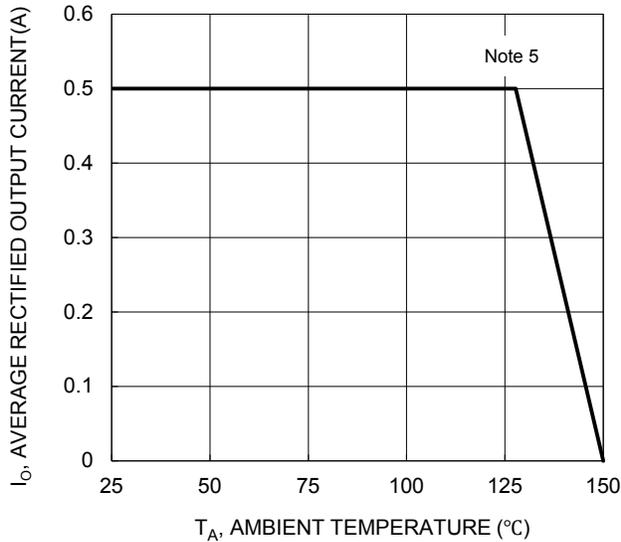


Figure 3. DC Forward Current Derating

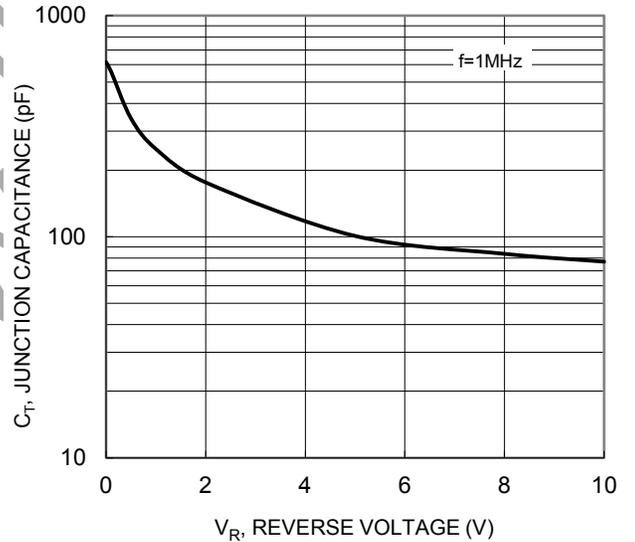
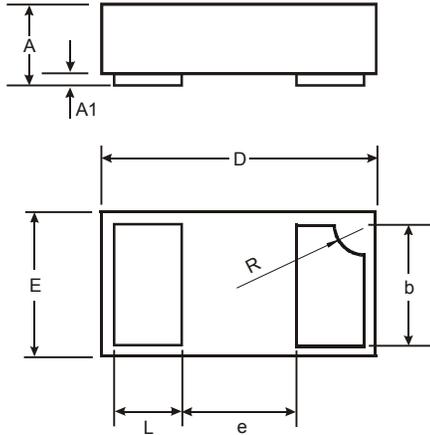


Figure 4. Typical Junction Capacitance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X1-DFN1006-2

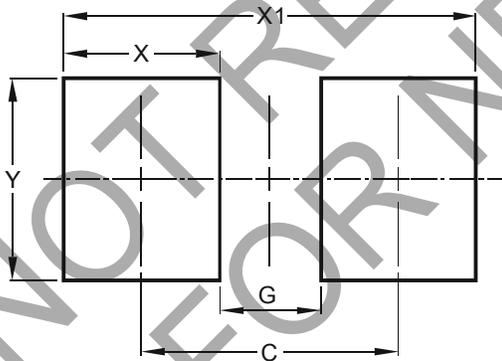


X1-DFN1006-2			
Dim	Min	Max	Typ
A	0.47	0.53	0.50
A1	0	0.05	0.03
b	0.45	0.55	0.50
D	0.95	1.075	1.00
E	0.55	0.675	0.60
e	–	–	0.40
L	0.20	0.30	0.25
R	0.05	0.15	0.10
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X1-DFN1006-2



Dimensions	Value (in mm)
C	0.70
G	0.30
X	0.40
X1	1.10
Y	0.70

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